

June 1993 Revised April 2005

74LVX573

Low Voltage Octal Latch with 3-STATE Outputs

General Description

The LVX573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{\text{OE}}$) inputs. The LVX573 is functionally identical to the LVX373 but with inputs and outputs on opposite sides of the package. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

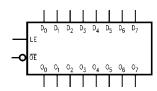
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

Order Number	Package Number	Package Description
74LVX573M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX573SJ	M20D	Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.

Logic Symbols

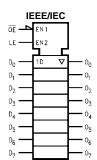


Connection Diagram



Pin Descriptions

Pin	Names	Description
D ₀ -D ₇		Data Inputs
LE		Latch Enable Input
OE		3-STATE Output Enable Input
O ₀ -O ₇		3-STATE Latch Outputs



Functional Description

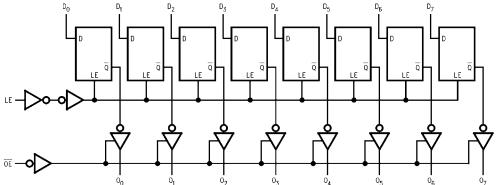
The LVX573 contains eight D-type latches. When the enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The $\underline{\mbox{ 3-STATE}}$ buffers are controlled by the Output Enable (OE) input. When \overline{OE} is LOW, the buffers are enabled. When \overline{OE} is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

	Outputs		
ŌĒ	LE	D	O _n
L	Н	Н	Н
L	Н	L	L
L	L	X	O ₀
Н	X	X	Z

- H = HIGH Voltage
- L = LOW Voltage Z = High Impedance
- $O_0 = \hbox{Previous} \ O_0 \ \hbox{before HIGH-to-LOW transition of Latch Enable}$

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5V to +7.0V

DC Input Diode Current (I_{IK})

 $V_{I} = -0.5 V \\ DC \ Input \ Voltage \ (V_{I}) \\ -0.5 V \ to \ 7 V$

DC Output Diode Current (I_{OK})

 $V_{O} = -0.5V \\ V_{O} = V_{CC} + 0.5V \\ +20 \text{ mA}$

DC Output Voltage (V_{O}) -0.5V to $V_{CC} + 0.5V$

DC Output Source

or Sink Current (I_O) ±25 mA

DC V_{CC} or Ground Current

 $\begin{array}{ll} (I_{CC} \mbox{ or } I_{GND}) & \pm 75 \mbox{ mA} \\ \mbox{Storage Temperature } (T_{STG}) & -65 \mbox{°C to } +150 \mbox{°C} \end{array}$

Power Dissipation 180 mW

Recommended Operating Conditions (Note 2)

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{cc}	T _A = +25°C		$T_A = -40$ °C to $+85$ °C		Units	Conditions		
Cynnbon	i arameter	-66	Min	Тур	Max	Min	Max	Omis	Conditions	
V _{IH}	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V _{IL}	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V _{OH}	HIGH Level	2.0	1.9	2.0		1.9			$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu\text{A}$ $I_{OH} = -50 \mu\text{A}$ $I_{OH} = -4 \text{ mA}$	
	Output Voltage	3.0	2.9	3.0		2.9		V	$I_{OH} = -50 \mu A$	
		3.0	2.58			2.48			$I_{OH} = -4 \text{ mA}$	
V _{OL}	LOW Level	2.0		0.0	0.1		0.1		$V_{IN} = V_{IH} \text{ or } V_{IL} I_{OL} = 50 \mu\text{A}$	
	Output Voltage	3.0		0.0	0.1		0.1	V	$I_{OL} = 50 \mu A$	
		3.0			0.36		0.44		$I_{OL} = 4 \text{ mA}$	
I _{OZ}	3-STATE Output	3.6			±0.25		±2.5	μΑ	$V_{IN} = V_{IH}$ or V_{IL}	
	Off-State Current								V _{OUT} = V _{CC} or GND	
I _{IN}	Input Leakage Current	3.6			±0.1		±1.0	μΑ	V _{IN} = 5.5V or GND	
I _{CC}	Quiescent Supply Current	3.6			4.0		40.0	μΑ	V _{IN} = V _{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V _{CC}	T _A = 25°C		Units	C _L (pF)	
		(V)	Тур	Limit	• • • • • • • • • • • • • • • • • • • •	- L (F-)	
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	0.5	0.8	V	50	
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}		-0.5	-0.8	V	50	
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50	
V _{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50	

Note 3: (Input $t_r = t_f = 3ns$)

AC Electrical Characteristics

Symbol	Parameter	V _{CC}	T _A = +25°C			T _A = -40°	C to +85°C	Units	Conditions	
Зупівої		(V)	Min	Тур	Max	Min	Max	Ullits	Conditions	
t _{PLH}	Propagation	2.7		7.6	14.5	1.0	17.5		C _L = 15 pF	
t _{PHL}	Delay Time			10.1	18.0	1.0	21.0	ns	C _L = 50 pF	
	D _n to O _n	3.3 ± 0.3		5.9	9.3	1.0	11.0	115	C _L = 15 pF	
				8.4	12.8	1.0	14.5		C _L = 50 pF	
t _{PLH}	Propagation	2.7		8.2	15.6	1.0	18.5		C _L = 15 pF	
t _{PHL}	Delay Time			10.7	19.1	1.0	22.0	ns	C _L = 50 pF	
	LE to O _n	3.3 ± 0.3		6.4	10.1	1.0	12.0	115	C _L = 15 pF	
				8.9	13.6	1.0	15.5		C _L = 50 pF	
t _{PZL}	3-STATE Output	2.7		7.8	15.0	1.0	18.5		$C_L = 15 \text{ pF}, R_L = 1 \text{ k}\Omega$	
t_{PZH}	Enable Time			10.3	18.5	1.0	22.0	ns	$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$	
		3.3 ± 0.3		6.1	9.7	1.0	12.0	115	$C_L = 15 \text{ pF}, R_L = 1 \text{ k}\Omega$	
				8.6	13.2	1.0	15.5		$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$	
t _{PLZ}	3-STATE Output	2.7		12.1	19.1	1.0	22.0	ns	$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$	
t_{PHZ}	Disable Time	3.3 ± 0.3		10.1	13.6	1.0	15.5	115	$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$	
t _W	LE Pulse	2.7	6.5			7.5		ns		
	Width	3.3 ± 0.3	5.0			5.0		115		
t _S	Setup Time	2.7	5.0			5.0		ns		
	D _n to LE	3.3 ± 0.3	3.5			3.5		115		
t _H	Hold Time	2.7	1.5			1.5		ns		
	D _n to LE	3.3 ± 0.3	1.5			1.5		115		
t _{OSHL}	Output to Output	2.7			1.5		1.5	ns	C _L = 50 pF	
toslh	Skew (Note 4)	2.3			1.5		1.5	115		

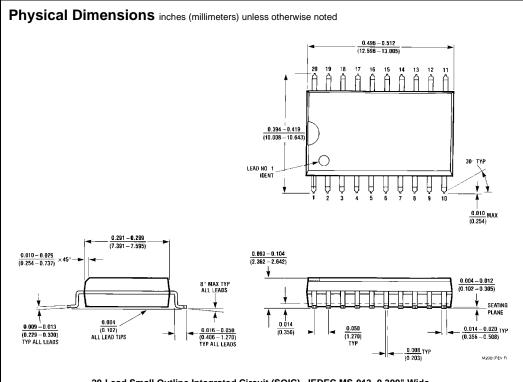
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|.$

Capacitance

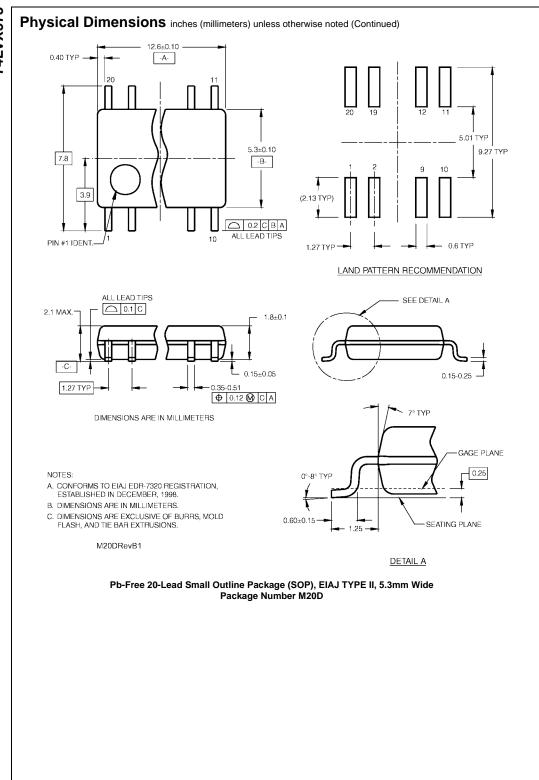
Symbol	Parameter		T _A = +25°C		T _A = -40°0	Units	
		Min	Тур	Max	Min	Max	Oilles
C _{IN}	Input Capacitance		4	10		10	pF
C _{OUT}	Output Capacitance		6				pF
C _{PD}	Power Dissipation		27				pF
	Capacitance (Note 5)						

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

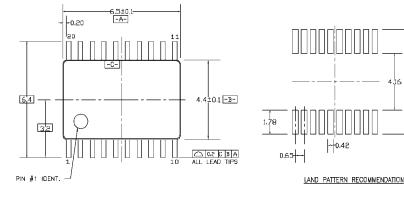
Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{|N} + I_{CC}}{8 \text{ (per latch)}}$

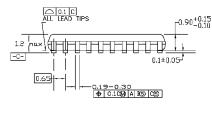


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Package Number M20B



Physical Dimensions inches (millimeters) unless otherwise noted (Continued)







SEE DETAIL A

DIMENSIONS ARE IN MILLIMETERS

NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MD-153, VARIATION AC, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND THE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M. 1982.

0 - 8.7 GAGE PLANE 0 - 8.7 GAGE PLANE 0.25 PLANE R0.09min DETAIL A

MTC20REVD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

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